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Diodes Incorporated DMP3012LPS-13

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DMP3012LPS

P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI[®]5060-8

Product Summary

V _{(BR)DSS}	R _{DS(ON)}	Ι _D T _C = +25°C
-30V	9mΩ @ V _{GS} = -10V	-45A
	12mΩ @ V _{GS} = -4.5V	-35A

Description and Applications

This new generation 30V P-Channel Enhancement Mode MOSFET has been designed to minimize $R_{DS(ON)}$ and yet maintain superior switching performance. This device is ideal for use in Notebook battery power management and loadswitch.

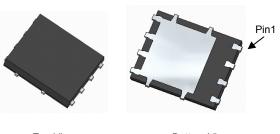
- Notebook Battery Power Management
- DC-DC Converters
- Loadswitch

Features and Benefits

- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low _{RDS(ON)} Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- ESD HBM Protected up to 1kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

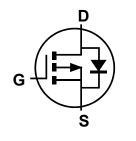
- Case: POWERDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Weight: 0.097 grams (approximate)

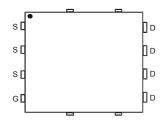


POWERDI5060-8

Top View

Bottom View





Internal Schematic

Top View Pin Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3012LPS-13	POWERDI5060-8	2500 / Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



) | | = Manufacturer's Marking P3012LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 13 = 2013) WW = Week (01 - 53)

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DMP3012LPS

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-30	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V_{GS} = -10V	Steady State	T _A = +25°C T _A = +70°C	ID	13.2 10.5	А
Continuous Drain Current (Note 6) V_{GS} = -4.5V	Steady State	T _A = +25°C T _A = +70°C	Ι _D	11.4 9.1	А
Pulsed Drain Current (Notes 6)			IDM	-100	А
Avalanche Current (Notes 7) L = 1mH			I _{AR}	-24	А
Avalanche Energy (Notes 7) L = 1mH			E _{AR}	292	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1.29	W
Thermal Resistance, Junction to Ambient @ $T_A = +25^{\circ}C$ (Note 5)	R _{0JA}	97	°C/W
Power Dissipation (Note 6)	PD	2.36	W
Thermal Resistance, Junction to Ambient @ $T_A = +25^{\circ}C$ (Note 6)	R _{0JA}	53	°C/W
Thermal Resistance, Junction to Case @ T_C = +25°C (Notes 6)	Rejc	4.0	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

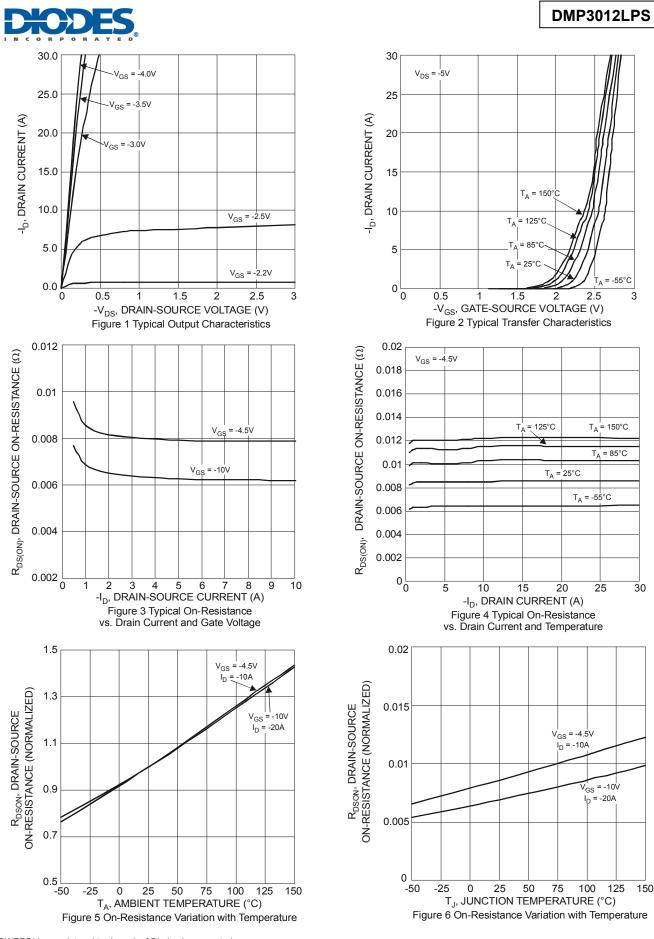
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1.0	μA	V _{DS} = -30V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}		—	±100	nA	V _{GS} = ±20V, V _{DS} = 0V	
ON CHARACTERISTICS (Note 8)						÷	
Gate Threshold Voltage	V _{GS(th)}	-1.1	-1.6	-2.1	V	V_{DS} = V_{GS} , I_D = -250 μ A	
Static Drain-Source On-Resistance	Deserve	_	7.5	9.0	mΩ	V _{GS} = -10V, I _D = -10A	
	R _{DS (ON)}	—	8.5	12.0		V _{GS} = -4.5V, I _D = -10A	
Forward Transfer Admittance	Y _{fs}	—	30	—	S	V _{DS} = -15V, I _D = -10A	
Diode Forward Voltage	V _{SD}	—	-0.65	-1.0	V	V _{GS} = 0V, I _S = -1A	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	_	6807	—	pF		
Output Capacitance	Coss	—	988	—	pF	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	—	647	—	pF		
Gate Resistance	Rg	_	6.2	—	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz	
Total Gate Charge (V _{GS} = -10V)	Qg	—	139	—	nC		
Total Gate Charge (V _{GS} = -4.5V)	Qg	—	66	—	nC		
Gate-Source Charge	Qgs	_	19	_	nC	– V _{DS} = -15V, I _D = -10A	
Gate-Drain Charge	Q _{gd}	_	21	_	nC	7	
Turn-On Delay Time	t _{D(on)}		8.9	_	ns		
Turn-On Rise Time	tr	_	10.5		ns	V _{DS} = -15V, V _{GEN} = -10V,	
Turn-Off Delay Time	t _{D(off)}		254	_	ns	R _G = 6Ω, I _D = -1A	
Turn-Off Fall Time	t _f		95	_	ns	1	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
7. Ias and Eas rating are based on low frequency and duty cycles to keep T_J = 25°C
8. Short duration pulse test used to minimize self-heating effect. Notes:

9. Guaranteed by design. Not subject to product testing.

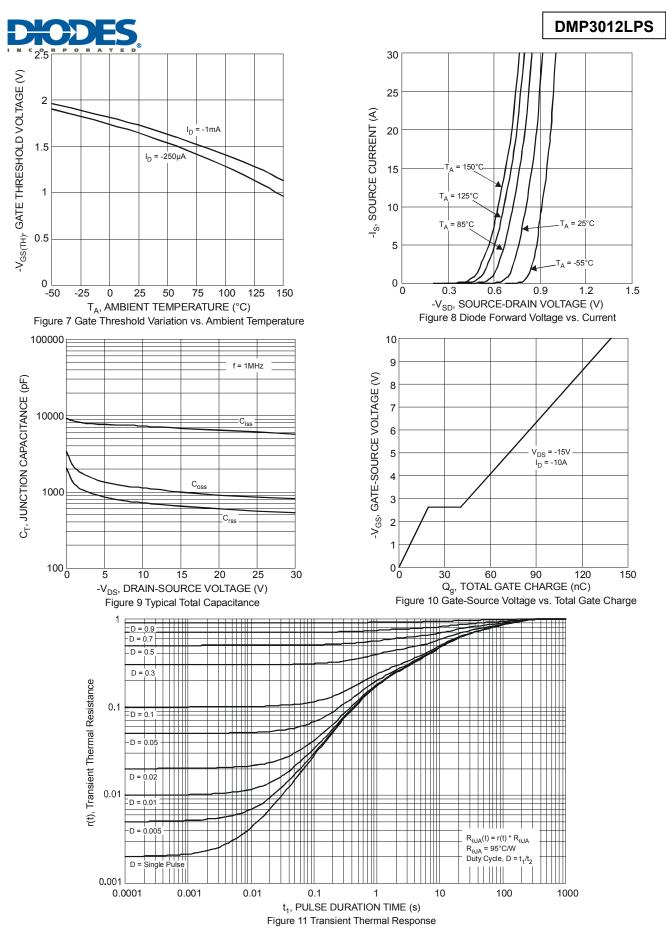




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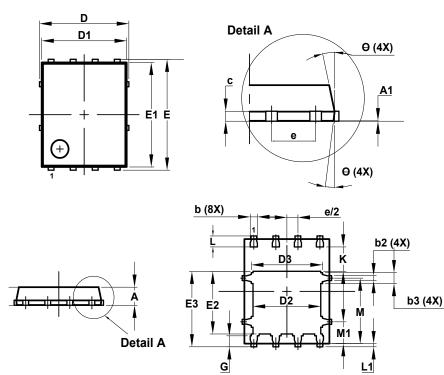




DMP3012LPS

Package Outline Dimensions

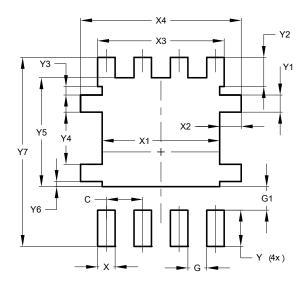
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI5060-8				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0.00	0.05	-	
b	0.33	0.51	0.41	
b2	0.200	0.350	0.273	
b3	0.40	0.80	0.60	
С	0.230	0.330	0.277	
D	-	5.15 BS0	-	
D1	4.70	5.10	4.90	
D2	3.70	4.10	3.90	
D3	3.90	4.30	4.10	
Е	6	6.15 BS(0	
E1	5.60	6.00	5.80	
E2	3.28	3.68	3.48	
E3	3.99	4.39	4.19	
е	1	.27 BS0	0	
G	0.51	0.71	0.61	
К	0.51		-	
L	0.51	0.71	0.61	
L1	0.10	0.20	0.175	
Μ	3.235	4.035	3.635	
M1	1.00	1.40	1.21	
Θ	10°	12°	11°	
Θ1	6°	8°	7°	
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
X3	4.420			
X4	5.610			
Y	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			





DMP3012LPS

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